



BCH65S016D2

Silicon Carbide Schottky Diode

650V, 16A

Description

BCH65S016D2 utilizes Bestirpower's advanced silicon carbide diode technology. This technology combines the benefits of excellent low forward voltage and robustness. Consequently, the family is suitable for application requiring high power efficiency

Benefits

- High-speed switching
- Low heat dissipation requirements
- Reduce size and cost of the system
- High-reliability
- System efficiency improvement

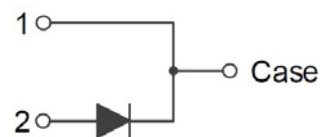
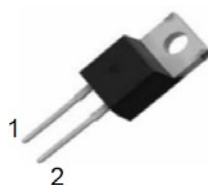
Applications

- Solar inverter
- Power factor correction
- Uninterruptible & AUX power supplies
- Switch mode power supply

Features

V_{RRM}	I_F	T_C	Q_C
650 V	16 A	154°C	48 nC

- High surge current capability
- No reverse recovery
- Positive temperature coefficient
- Benchmark switching behavior
- RoHS compliant / Halogen-free



Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		650	V
I_F	Forward Current	$T_C = 25^\circ\text{C}$	51	A
		$T_C = 135^\circ\text{C}$	24	A
		$T_C = 154^\circ\text{C}$	16	A
$I_{F,SM}$	Non-Repetitive Forward Surge Current	$T_C = 25^\circ\text{C}, t_p = 10 \text{ ms}$	120	A
		$T_C = 110^\circ\text{C}, t_p = 10 \text{ ms}$	100	A
$I_{F,RM}$	Repetitive Peak Forward Surge Current	$T_C = 25^\circ\text{C}, t_p = 10 \text{ ms}$	103	A
I^2dt value	$\int I^2 dt$	$T_C = 25^\circ\text{C}, t_p = 10 \text{ ms}$	72	A^2s
		$T_C = 110^\circ\text{C}, t_p = 10 \text{ ms}$	50	A^2s
P_{tot}	Power Dissipation	$T_C = 25^\circ\text{C}$	214	W
		$T_C = 110^\circ\text{C}$	93	W
		$T_C = 150^\circ\text{C}$	36	W
T_J, T_{STG}	Operating Junction and Storage Temperature		-55 to +175	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Typ.	0.7	°C/W

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{DC}	DC blocking voltage		650	-	-	V
V _F	Forward Voltage	I _F =8A	-	1.20	-	V
		I _F =16A, T _C =25°C	-	1.43	1.6	
		I _F =16A, T _C =175°C	-	1.72	-	
I _R	Reverse Current	V _R = 650 V, T _C = 25°C	-	7	100	µA
		V _R = 650 V, T _C = 175°C	-	15	-	
Q _C	Total Capacitive Charge	V _R = 400 V, T _C = 25°C	-	48	-	nC
C	Total Capacitance	V _R = 1V, f=1MHz	-	659	-	pF
		V _R = 200V, f=1MHz	-	96	-	
		V _R = 400V, f=1MHz	-	95	-	
E _C	Capacitance Stored Energy	V _R = 400V	-	8	-	µJ

Package Marking and Ordering Information

Part Number	Top Marking	Package	Packing Method	Quantity
BCH65S016D2	BCH65S016D2	TO220-2	Tube	50 units

Typical Performance Characteristics

Figure 1. Forward Characteristics

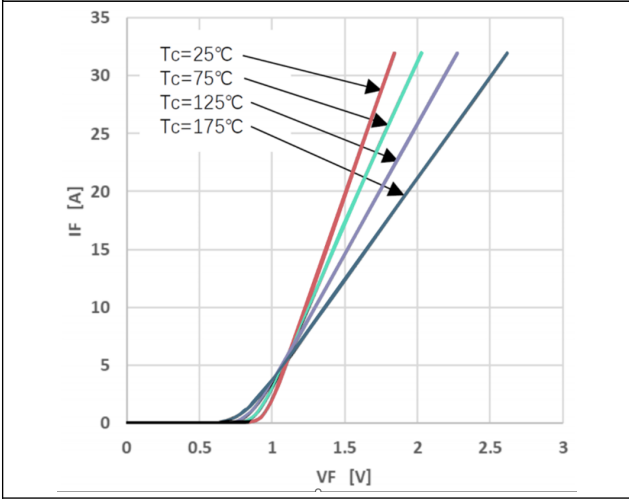


Figure 2. Reverse Characteristics

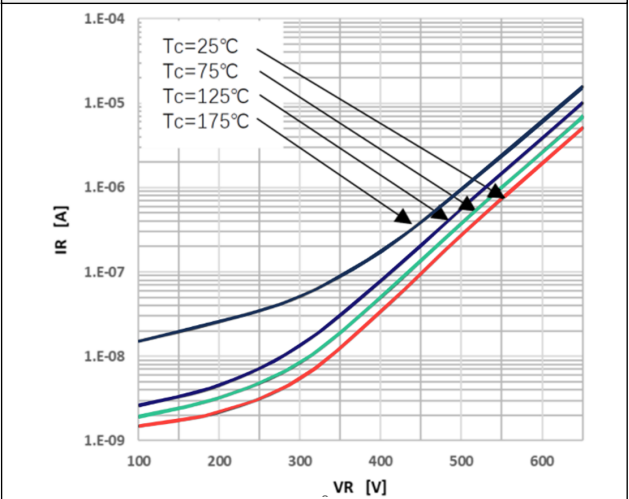


Figure 3. Peak Forward Current Derating

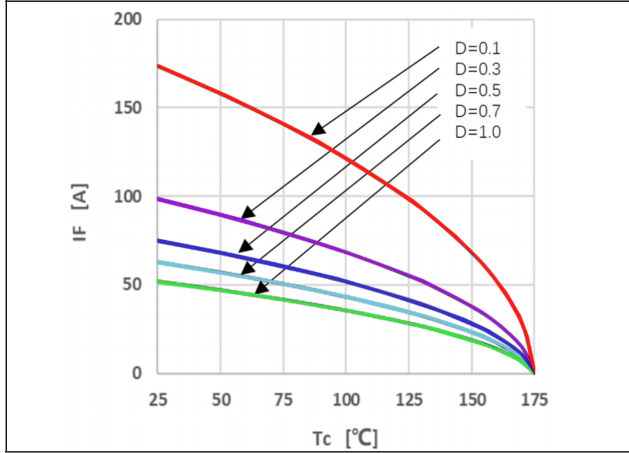


Figure 4. Power Dissipation

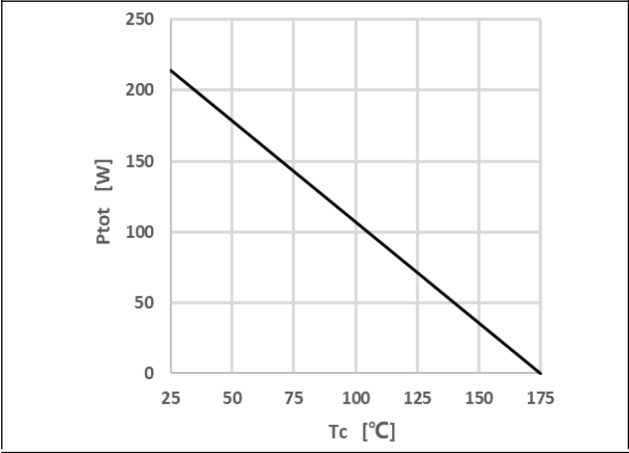


Figure 5. Capacitance vs. Reverse Voltage

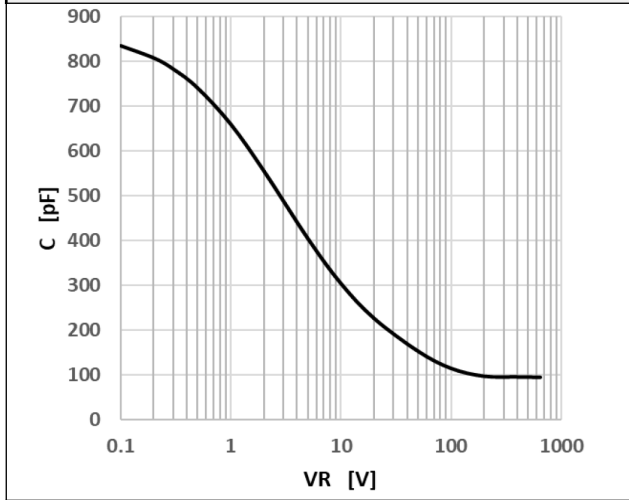
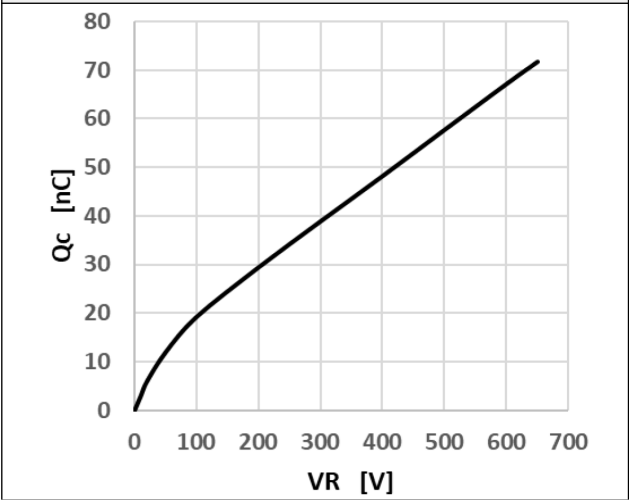


Figure 6. Capacitance Charge vs. Reverse Voltage



Typical Performance Characteristics

Figure 7. Capacitance Stored Energy

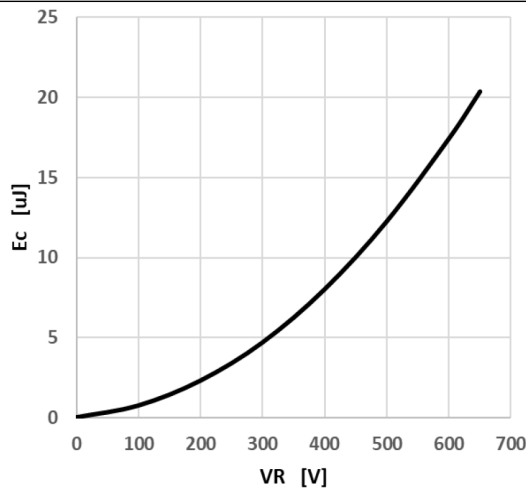
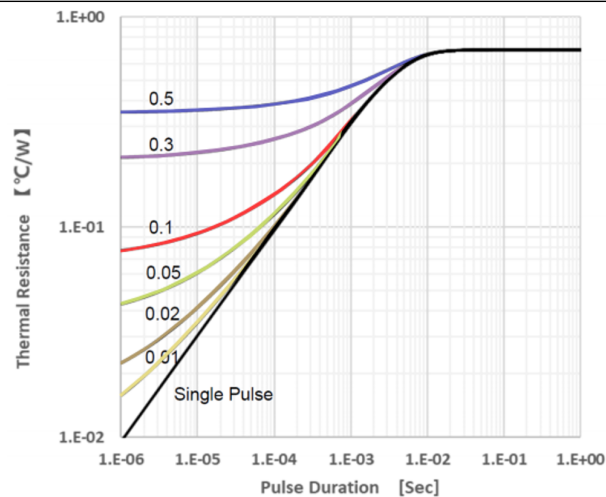
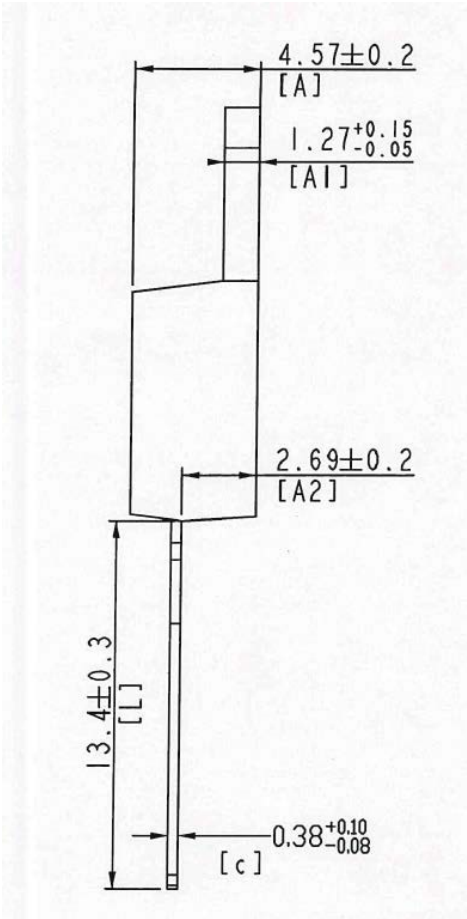
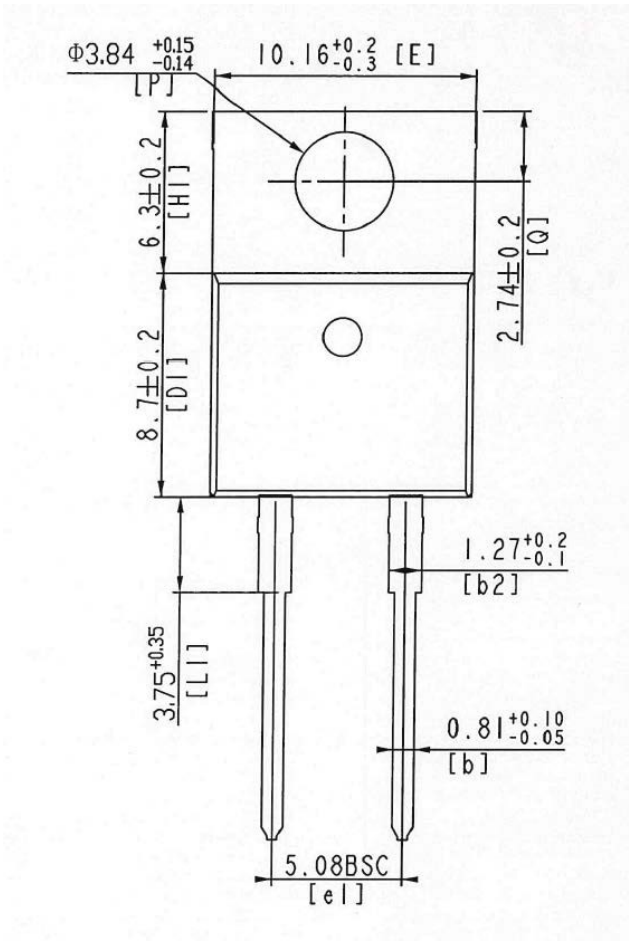


Figure 8. Transient Thermal Impedance



Package Outlines
TO220-2



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